EVQ4560-N-00A

2A, 55V, 2MHz
Step-Down Converter Evaluation Board

The Future of Analog IC Technology

DESCRIPTION

The EVQ4560-N-00A is an evaluation board for the MPQ4560, a high frequency step-down regulator with an integrated power MOSFET.

The MP4560 integrates a 250mΩ MOSFET that provides 2A load current over a wide operating input voltage of 4.5V to 55V.

Current mode control provides fast transient response and eases loop stabilization. An internal soft-start prevents inrush current at turn-on.

The EVQ4560-N-00A is a fully assembled and tested PCB. It generates a +5V output voltage at load current up to 2A from an 8V to 55V input range. Switching frequency is set at 700kHz.

ELECTRICAL SPECIFICATIONS

Parameter	Symbol	Value	Units
Input Voltage	V_{IN}	8 – 55	V
Output Voltage	V_{OUT}	5	V
Output Current	I_{OUT}	2	A

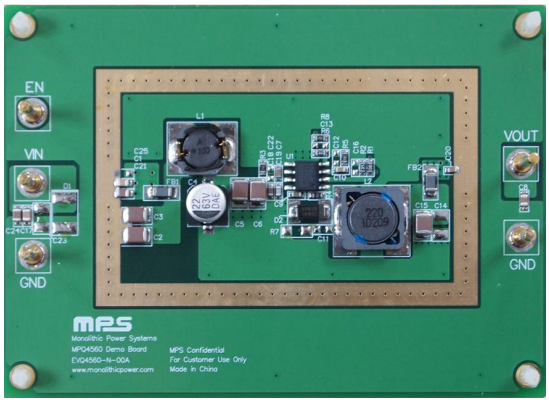
FEATURES

- 2A Output Current
- Programmable Switching Frequency up to 2MHz
- Wide 8V to 55V Operating Input Range
- Adjustable Output from 0.8V
- Fully Assembled and Tested

APPLICATIONS

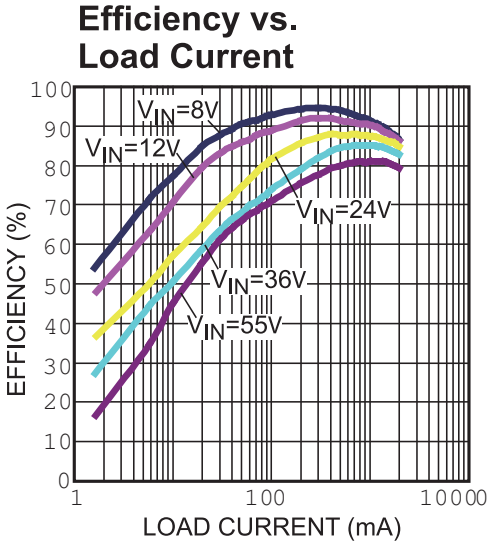
- High Voltage Power Conversion
- Game Machines
- Automotive Systems
- Industrial Power Systems
- Distributed Power Systems
- Printer Systems
- Battery Powered Systems

EVQ4560-N-00A EVALUATION BOARD

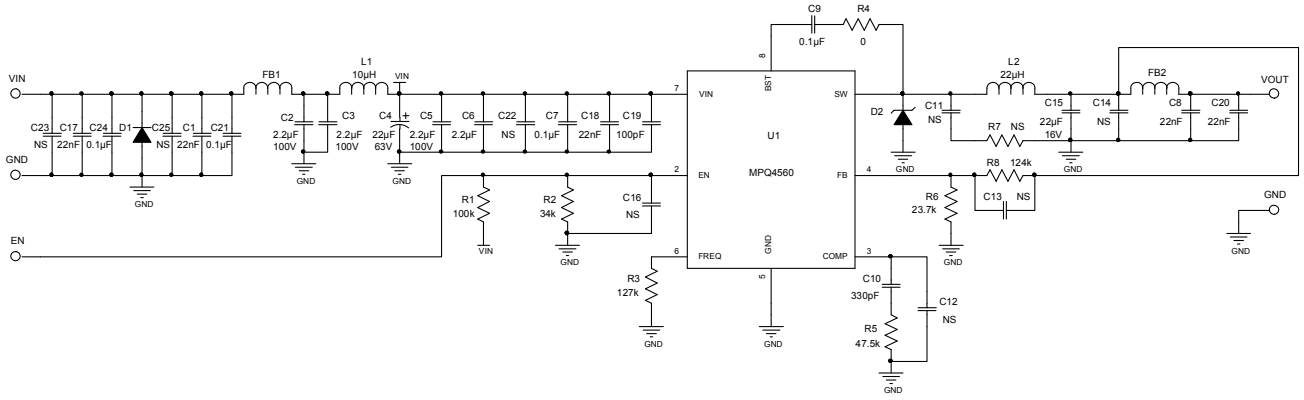


(L x W x H) 3.5" x 2.5" x 0.4"
(8.8cm x 6.4cm x 1.0cm)

Board Number	MPS IC Number
EVQ4560-N-00A	MPQ4560DN



EVALUATION BOARD SCHEMATIC



EVQ4560-N-00A BILL OF MATERIALS

Qty	RefDes	Value	Description	Package	Manufacturer	Manufactuer_P/N
2	C1, C17	22nF	Ceramic Capacitor; 100V; X7R; 0805	0805	TDK	C2012X7R2A223K
4	C2, C3, C5, C6	2.2µF	Ceramic Capacitor; 100V; X7R; 1210	1210	TDK	C3225X7R2A225K
1	C4	22µF	Electrolytic Capacitor; 63V; Φ6.3mmx7.7mm(H)	SMD	Jianghai	VTD-63V22
2	C7, C9	0.1µF	Ceramic Capacitor; 100V; X7R; 0603	0603	muRata	GRM188R72A104KA 35D
1	C8	22nF	Ceramic Capacitor; 50V; X7R; 0805	0805	TDK	C2012X7R1H223K
1	C10	330pF	Ceramic Capacitor; 50V; X7R; 0603	0603	TDK	C1608X7R1H331K
1	C15	22µF	Ceramic Capacitor; 16V; X7R; 1210	1210	TDK	C3235X7R1C226M
1	C18	22nF	Ceramic Capacitor; 100V; X7R; 0603	0603	TDK	C1608X7R2A223K
1	C19	100pF	Ceramic Capacitor; 100V; C0G; 0603	0603	TDK	C1608C0G2A101J
1	C20	22nF	Ceramic Capacitor; 50V; X7R; 0603	0603	TDK	C1608X7R1H223K
2	C21, C24	0.1µF	Ceramic Capacitor; 100V; X7R; 0805	0805	TDK	C2012X7R2A104K
2	C11, C25	NS		0805		
4	C12, C13, C16, C22	NS		0603		
2	C14, C23	NS		1210		
1	D1	NS		SMB		
1	D2	B260A	Diode Schottky; 60V; 2A	SMA	Diodes	B260A
5	EN, GND1, GND2, VIN, VOUT		2.0 Golden Pin		HZ	

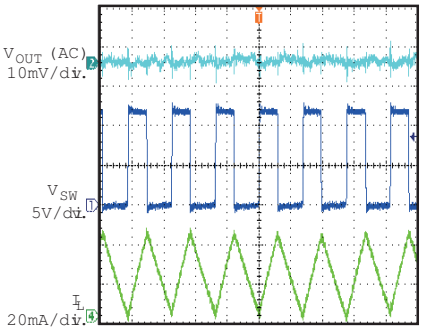
EVQ4560-N-00A BILL OF MATERIALS *(continued)*

Qty	RefDes	Value	Description	Package	Manufacturer	Manufactuer_P/N
2	FB1, FB2		Magnetic Bead; 6A	1206	muRata	BLM31PG330SH1L
1	L1	10μH	Inductor; 2.4A	SMD	TOKO	DS85LCB-B1135AS -100M
1	L2	22μH	Inductor; 3A	SMD	TOKO	D104C-919AS-220M
1	R1	100k	Film Resistor; 1%	0603	Yageo	RC0603FR-07100KL
1	R2	34k	Film Resistor; 1%	0603	Yageo	RC0603FR-0734KL
1	R3	127k	Film Resistor; 1%	0603	Yageo	RC0603FR-07127KL
1	R4	0	Film Resistor; 5%	0603	Yageo	RC0603JR-070RL
1	R5	47.5k	Film Resistor; 1%	0603	Yageo	RC0603FR-0747K5L
1	R6	23.7k	Film Resistor; 1%	0603	Yageo	RC0603FR-0723K7L
1	R7	NS		0603		
1	R8	124k	Film Resistor; 1%	0603	Yageo	RC0603FR-07124KL
1	U1	MPQ4560DN	Step-Down Regulator	SO8/EP	MPS	MPQ4560DN

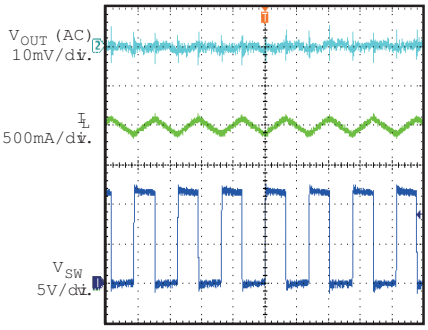
EVB TEST RESULTS

Performance waveforms are tested on the evaluation board.
V_{IN} = 12V, V_{OUT} = 5V, T_A = 25°C, unless otherwise noted.

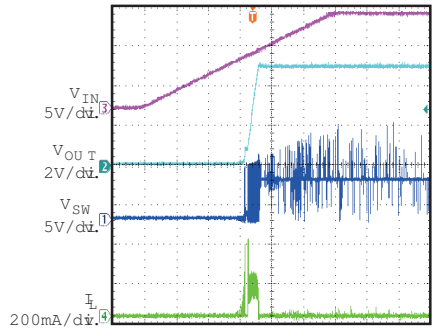
Output Ripple Voltage
I_{OUT} = 0.1A



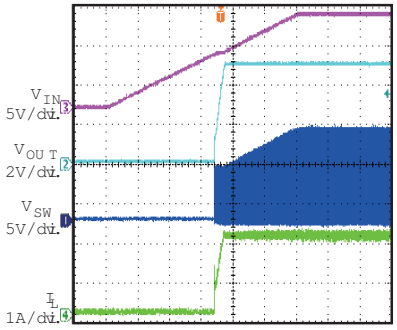
Output Ripple Voltage
I_{OUT} = 2A



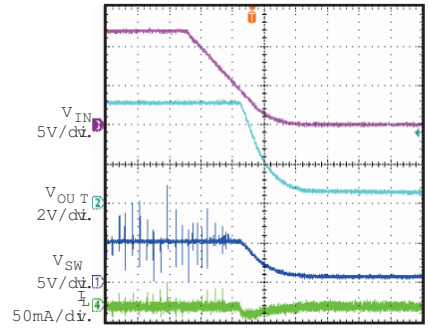
Power On
I_{OUT} = 0A



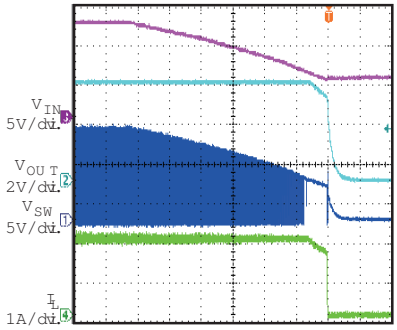
Power On
I_{OUT} = 2A



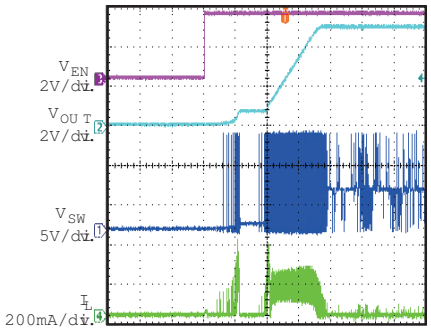
Power Off
I_{OUT} = 0A



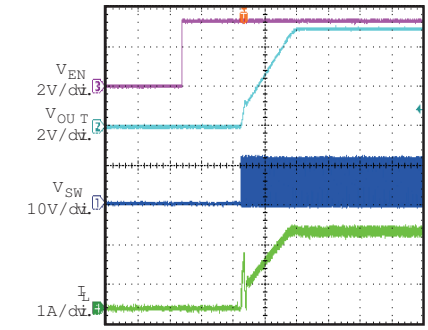
Power Off
I_{OUT} = 2A



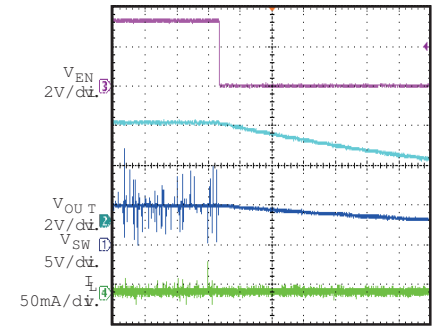
En On
I_{OUT} = 0A



En On
I_{OUT} = 2A



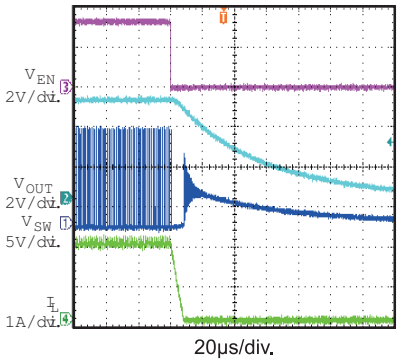
En Off
I_{OUT} = 0A



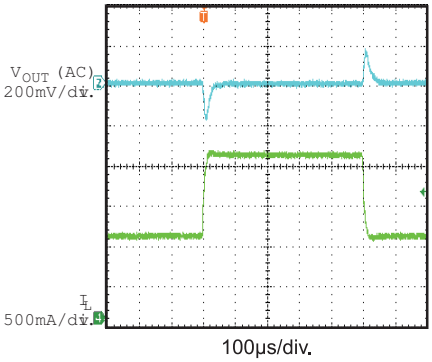
EVB TEST RESULTS *(continued)*

Performance waveforms are tested on the evaluation board.
V_{IN} = 12V, V_{OUT} = 5V, T_A = 25°C, unless otherwise noted.

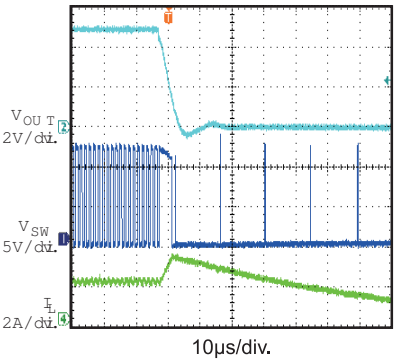
En Off
I_{OUT} = 2A



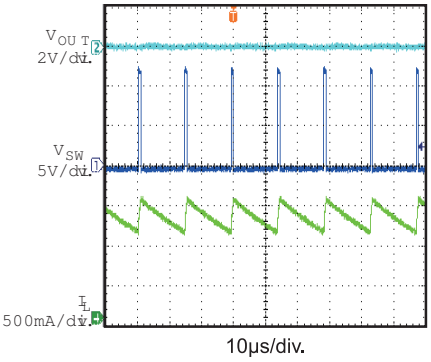
Load Transient Response
I_{OUT} = 1A to 2A



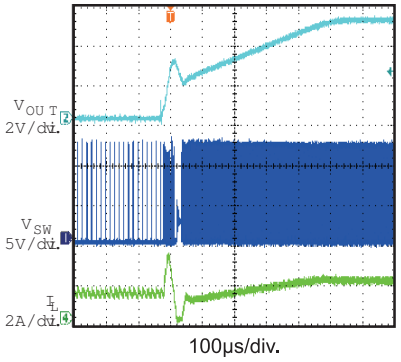
Short Entry
I_{OUT} = 2A



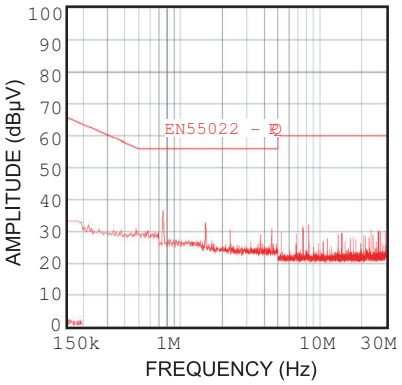
Short Steady State



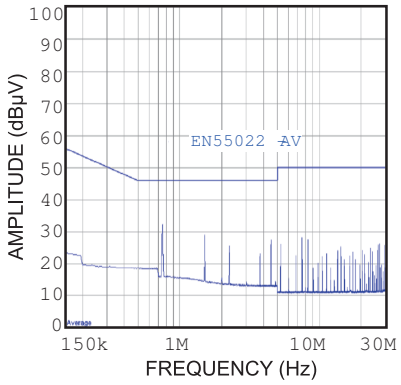
Short Recovery
I_{OUT} = 2A



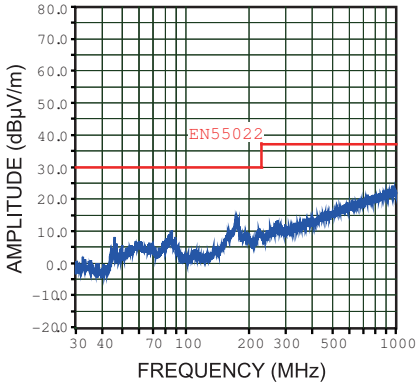
Conducted EMI - QP
V_{IN}=24V, I_{OUT}=2A, Reistor Load



Conducted EMI - AV
V_{IN}=24V, I_{OUT}=2A, Reistor Load



Radiated EMI
V_{IN}=24V, I_{OUT}=2A, Reistor Load



PRINTED CIRCUIT BOARD LAYOUT

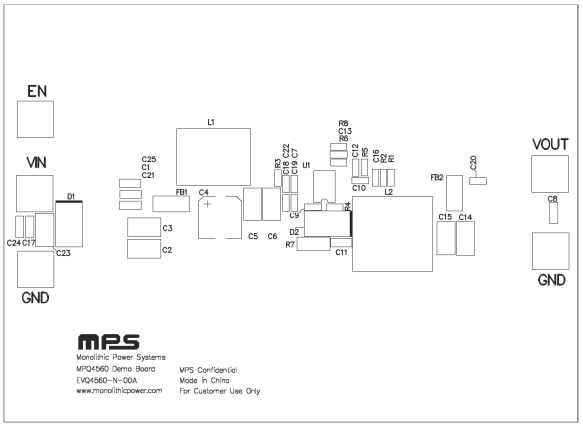


Figure 1—Top Silk Layer

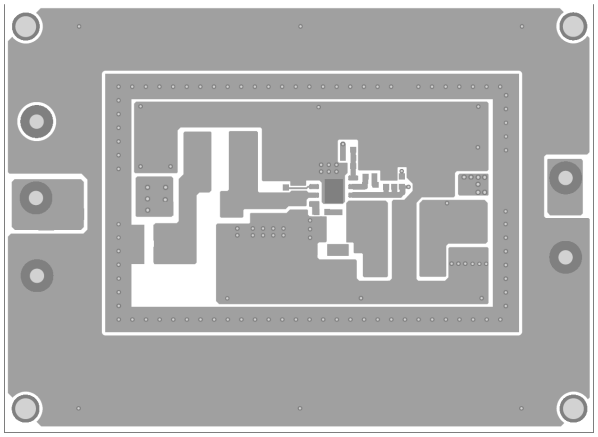


Figure 2—Top Layer

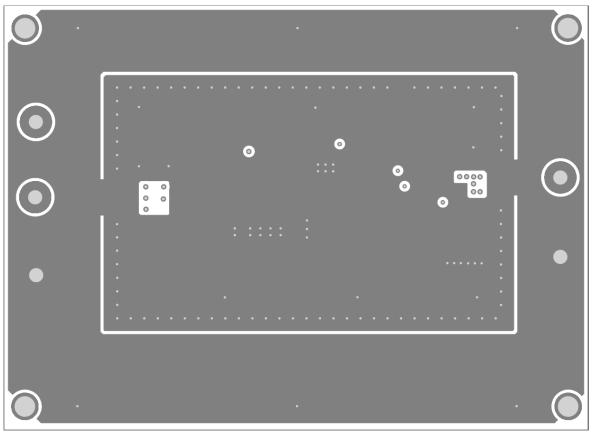


Figure 1—Inner1 Layer

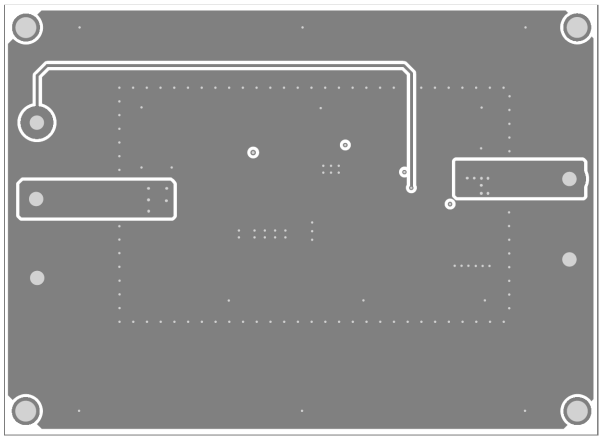


Figure 2—Inner2 Layer

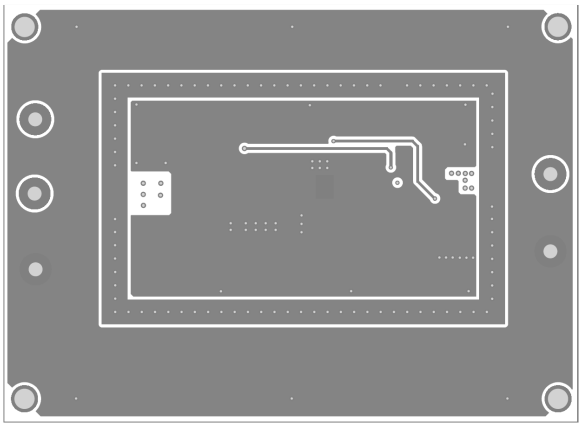


Figure 3—Bottom Layer

QUICK START GUIDE

1. Connect the positive and negative terminals of the load to the VOUT and GND pins, respectively.
2. Preset the power supply output to between 8 and 55V, and then turn it off.
3. Connect the positive and negative terminals of the power supply output to the VIN and GND pins, respectively.
4. Turn the power supply on. The MPQ4560DN will automatically startup.
5. To use the Enable function, apply a digital input to the EN pin. Drive EN higher than 1.55V to turn on the regulator, drive EN less than 1.23V to turn it off.
6. An input under voltage lockout (UVLO) function is implemented by the addition of a resistor divider R1 and R2. The EN threshold is 1.23V (falling edge), so V_{IN} UVLO threshold is $1.23V \times \left(1+\frac{R1}{R2}\right)$. It is preset to around 3.8V on this board.
7. Use R6 and R8 to set the output voltage with V_{FB} = 0.8V. For R6 = 23.7kΩ, R8 can be determined by: $R8 = 29.625 \times (V_{OUT} - 0.8)$ (kΩ). Follow the Application Information section in the device datasheet to recalculate the compensation, inductor and output capacitor values when output voltage is changed.